



**DMP2036UVT** 

#### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D Max</sub> T <sub>A</sub> = +25°C
-20V	30mΩ @ V <sub>GS</sub> = -4.5V	-6.0A
-20V	$39m\Omega @ V_{GS} = -2.5V$	-5.5A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- **DC-DC Converters**
- Motor Control
- **Power Management Functions**
- Analog Switch

#### **Features and Benefits**

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

P-CHANNEL ENHANCEMENT MODE MOSFET

Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.013 grams (Approximate)

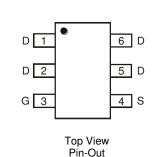


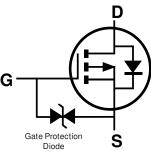


TSOT26



Top View





Equivalent Circuit

#### Ordering Information (Note 4)

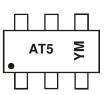
	Part Number	Case	Packaging			
	DMP2036UVT-7	TSOT26	3,000/Tape & Reel			
DMP2036UVT-13		TSOT26	10,000/Tape & Reel			
Notes:	s: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen - and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



AT5 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: F = 2018) M = Month (ex: 9 = September)

#### Date Code Kev

Year	2017	2018	20	019	2020	2021		2022	2023	20	24	2025
Code	E	F	_	G	H		•	J	K	L		 M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		<u>^</u>	•			•	-	~		-		5



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V <sub>DSS</sub>	-20	V	
Gate-Source Voltage		V <sub>GSS</sub>	±8	V	
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$	ID	-6.0 -5.0	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-40	А	
Continuous Source-Drain Diode Current (Note 6)		ls	-2,2	А	
Avalanche Current (Note 7) L = 0.1mH	valanche Current (Note 7) L = 0.1mH			-21	А
Avalanche Energy (Note 7) L = 0.1mH	E <sub>AS</sub>	23	mJ		

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Bower Dissipation (Note 5)	$T_A = +25^{\circ}C$	Р	1.1	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.7	vv
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	108	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	D	1.5	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.0	vv
Thermal Resistance, Junction to Ambient (Note 6) St		R <sub>0JA</sub>	81	°C/W
Thermal Resistance, Junction to Case (Note 6)	Steady State	R <sub>θJC</sub>	16	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

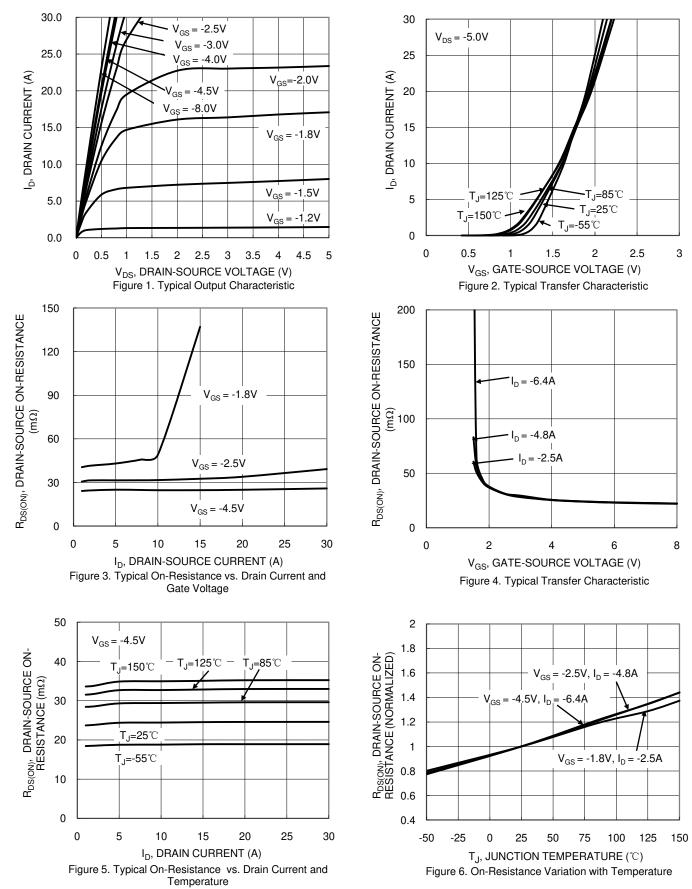
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						·	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	-	—	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	—	—	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						·	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4		-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
			24	30		$V_{GS} = -4.5V, I_D = -6.4A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	31	39	mΩ	$V_{GS} = -2.5V, I_D = -4.8A$	
			41	58		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -2.5A	
Diode Forward Voltage	V <sub>SD</sub>	—	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1.0A$	
DYNAMIC CHARACTERISTICS (Note 9)						·	
Input Capacitance	Ciss	—	1,808	—			
Output Capacitance	Coss	—	155	—	pF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	117	—			
Gate Resistance	Rg	—	32	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	—	20.5	—			
Gate-Source Charge	Q <sub>gs</sub>	—	2.8	—	nC	$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_{D} = -4.0A$	
Gate-Drain Charge	Q <sub>gd</sub>	—	4.1	—		$I_D = -4.0A$	
Turn-On Delay Time	t <sub>D(ON)</sub>	—	9.1	—			
Turn-On Rise Time	t <sub>R</sub>	_	12.3	_		$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	120	—	ns	$R_{g} = 6\Omega, I_{D} = -1.0A$	
Turn-Off Fall Time	tF	_	54	_	1	-	
Reverse Recovery Time	t <sub>RR</sub>	—	23.1	_	ns	I <sub>F</sub> = -1.0A, di/dt = 100A/µs	
Reverse Recovery Charge	Q <sub>BB</sub>	_	8.3	_	nC	I <sub>F</sub> = -1.0A, di/dt = 100A/µs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. 7. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}$ C.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



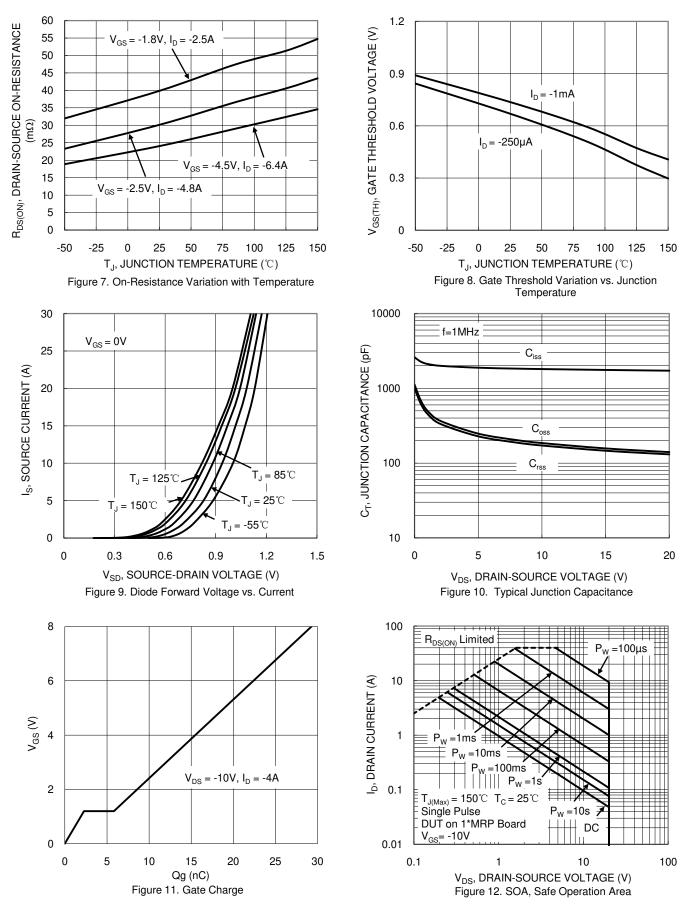
### **DMP2036UVT**



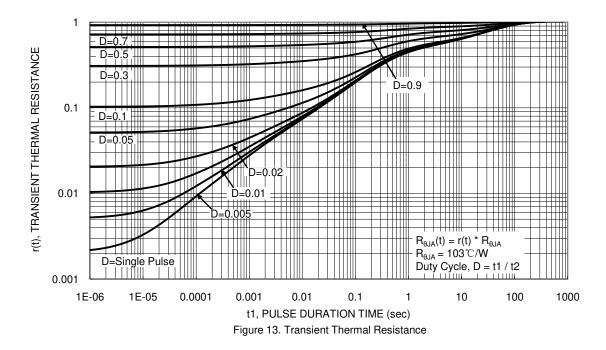
DMP2036UVT Document number: DS40059 Rev. 2 - 2



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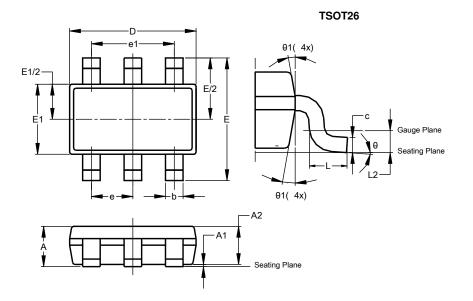






# **Package Outline Dimensions**

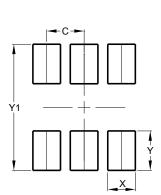
Please see http://www.diodes.com/package-outlines.html for the latest version.



TSOT26								
Dim	Min Max Typ							
Α	-	1.00	-					
A1	0.010	0.100	-					
A2	0.840	0.900	-					
D	2.800	3.000	2.900					
Е	2	.800 BS	С					
E1	1.500	1.700	1.600					
b	0.300	0.450	-					
С	0.120	0.200	-					
e	0	0.950 BSC						
e1	1	.900 BS	С					
L	0.30	0.50	-					
L2	0	.250 BS	С					
θ	0°	8°	4°					
θ1	4°	12°	-					
A	II Dimen	sions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



TSOT26

Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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